

FEATURES

1. This specification shall be applied to photocoupler. Model No. MOC3063 as an option.

2. Applicable Models (Business dealing name)

* Dual-in-line package :

MOC3063-V : 1-channel type

* Wide lead spacing package :

MOC3063M-V : 1-channel type

* Surface mounting package :

MOC3063S-V : 1-channel type

* Tape and reel packaging :

MOC3063S TA1-V

3. The relevant models are the models Approved by VDE
according to DIN VDE 0884:1992-06

Approved Model No.: MOC3063 / MOC3063M / MOC3063S /

VDE approved No.: 094722

(According to the specification DIN VDE 0884:1992-06)

* Operating isolation voltage V_{IORM} : 850V (Peak)

* Transient voltage V_{TR} : 6000V (Peak)

* Pollution : 2 (According to VDE 0110-1 : 1997-04)

* Clearances distance (Between input and output) : 7.0mm (MIN.)

* Creepage distance (Between input and output) : 7.0mm (MIN.)

* Isolation thickness between input and output : 0.4mm (MIN.)

* Safety limit values Current (Isi) : 400mA (Diode side)

Power (Psi) : 700mW (Phototransistor side)

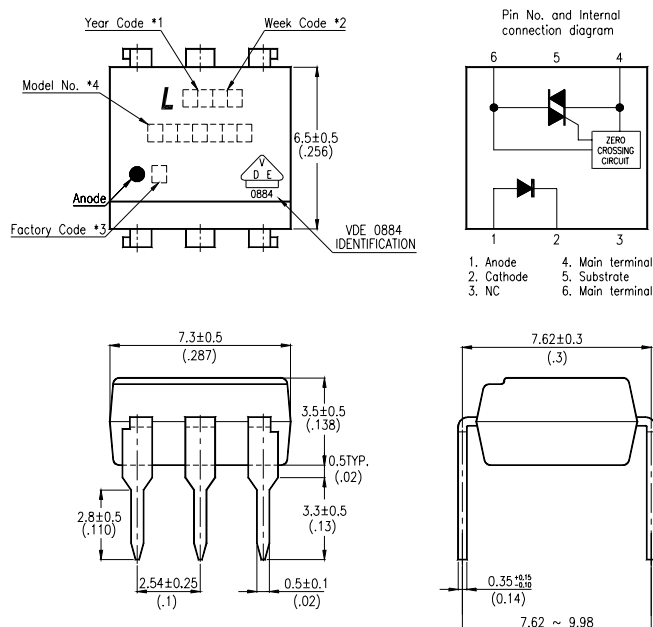
Temperature(Tsi) : 175°C

In order to keep safety electric isolation of photocoupler, please set the protective circuit to keep within safety limit values when the actual application equipment troubled.

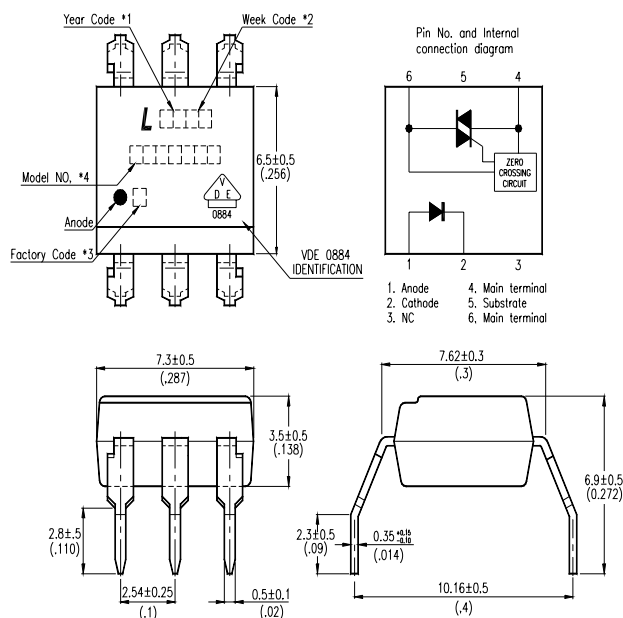
* Indication of VDE 0884 approval prints "  " on sleeve package.

OUTLINE DIMENSIONS

Dual-in-line package :



Wide lead spacing package:



*1. Year date code.

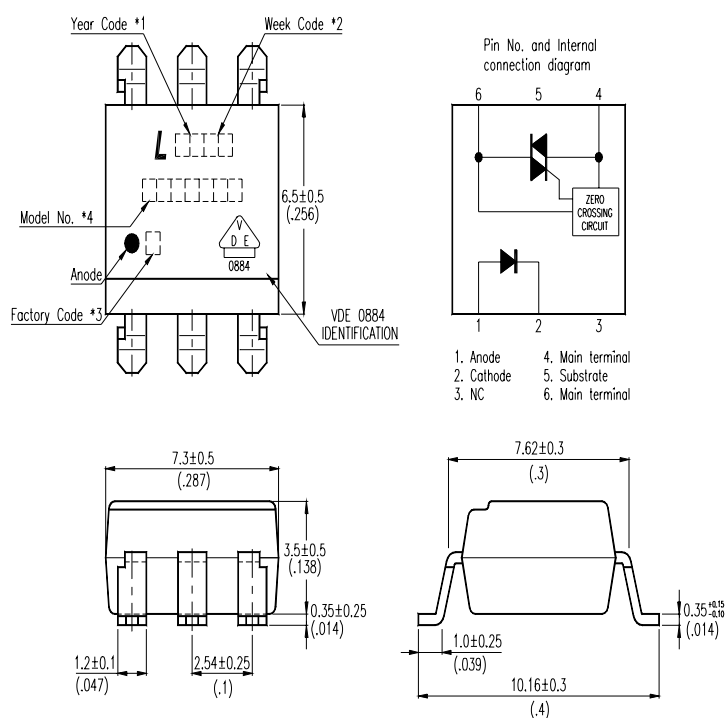
*2. 2-digit work week.

*3. Factory identification mark shall be marked (Z : Taiwan, Y : Thailand, X : China).

*4. Model No.: MOC3063

OUTLINE DIMENSIONS

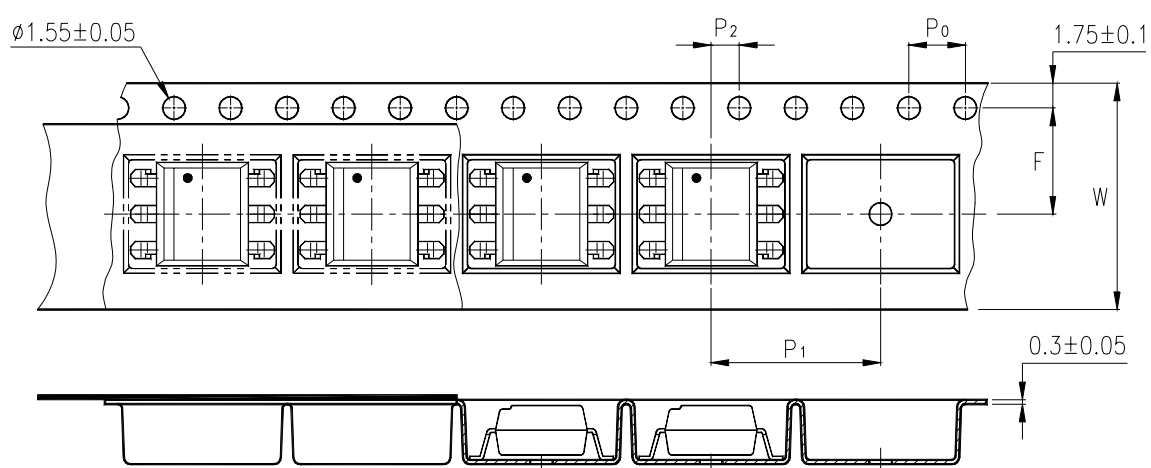
Surface mounting package :



- *1. Year date code.
- *2. 2-digit work week.
- *3. Factory identification mark shall be marked (Z : Taiwan, Y : Thailand, X : China).
- *4. Model MOC3063

TAPING DIMENSIONS

Tape and reel package (TYPE I):
MOC3063S-TA1



Description	Symbol	Dimensions in mm (inches)
Tape wide	W	16 ± 0.3 (.63)
Pitch of sprocket holes	P_0	4 ± 0.1 (.15)
Distance of compartment	F	7.5 ± 0.1 (.295)
Distance of compartment to compartment	P_1	2 ± 0.1 (.079)
	P_2	12 ± 0.1 (.472)

ABSOLUTE MAXIMUM RATING

(Ta = 25°C)

PARAMETER		SYMBOL	RATING	UNIT
INPUT	Forward Current	I _F	50	mA
	Reverse Voltage	V _R	6	V
	Power Dissipation	P _D	120	mW
OUTPUT	Off-State Output Terminal Voltage	V _{DRM}	600	V
	Peak Repetitive Surge Current (PW=100μs, 120pps)	I _{TSM}	1	A
	Collector Power Dissipation	P _C	150	mW
Total Power Dissipation		P _{tot}	250	mW
*1	Isolation Voltage	V _{iso}	5,000	V _{rms}
Ambient Operating Temperature Range		T _A	-40 ~ +100	°C
Storage Temperature Range		T _{stg}	-55 ~ +150	°C
*2	Soldering Temperature	T _L	260	°C

*1. AC For 1 Minute, R.H. = 40 ~ 60%

Isolation voltage shall be measured using the following method.

- (1) Short between anode and cathode on the primary side and between collector, emitter on the secondary side.
- (2) The isolation voltage tester with zero-cross circuit shall be used.
- (3) The waveform of applied voltage shall be a sine wave.

*2. For 10 Seconds

ELECTRICAL - OPTICAL CHARACTERISTICS

(Ta = 25°C)

PARAMETER		SYMBOL	MIN.	TYP.	MAX.	UNIT	CONDITIONS
INPUT	Forward Voltage	V_F	—	1.2	1.4	V	$I_F=20\text{mA}$
	Reverse Current	I_R	—	0.05	10	μA	$V_R=6\text{V}$
OUTPUT	*1 Peak Blocking Current, Either Direction	I_{DRM1}	—	—	500	nA	$V_{\text{DRM}} = 600\text{V}$
	Peak On-State Voltage, Either Direction	V_{TM}	—	—	3.0	V	$I_{\text{TM}}=100\text{ mA Peak}$
	*2 Critical rate of Rise of Off-State Voltage	Dv/dt	600	1500	—	V/ μs	
COUPLED	*3 Led Trigger Current, Current Required to Latch Output, Either Direction	I_{FT}	—	—	5	mA	Main Terminal Voltage = 3V
	Holding Current, Either Direction	I_H	—	400	—	μA	
	Turn-On Time	T_{ON}	—	8	20	μs	$V_P=9\text{V}$, $I_F=20\text{mA}$ $R_L = 100\Omega$
ZERO CROSSING	Inhibit Voltage	V_{INH}	—	5	20	Volts	$I_F=\text{Rated } I_{\text{FT}}$, MT1-MT2 Voltage above which device will not trigger.
	Leakage in Inhibited State	I_{DRM2}	—	—	500	μA	$I_F = \text{Rated } I_{\text{FT}}$, Rated V_{DRM} , Off State

*1 Test voltage must be applied within dv/dt rating.

*2 This is static dv/dt. Commutating dv/dt is a function of the load-driving thyristor(s) only.

*3 All devices are guaranteed to trigger at an I_F value less than or equal to max I_{FT} . Therefore, recommended operating I_F lies between max I_{FT} (5mA for MOC3063-V) and absolute max I_F (50mA)

ISOLATION SPECIFICATION ACCORDING TO VDE 0884

Parameter		Symbol	Conditions	Rating	Unit	Remark
Class of environmental test		-	DIN IEC68	30/100/21	-	
Pollution		-	DIN VDE0110	2	-	
Maximum Operating Isolation Voltage		V_{IORM}	-	850	V_{PEAK}	Refer to the Diagram 1, 2
Partial Discharge Test Voltage (Between Input and Output)	Diagram 1	V_{pr}	$t_p=60s, q_c<5pC$	1275	V_{PEAK}	
	Diagram 2		$t_p=1s, q_c<5pC$	1594	V_{PEAK}	
Maximum Over-voltage		$V_{INITIAL}$	$t_{INI} = 10s$	6000	V_{PEAK}	
Safety Maximum Ratings						Refer to the Figure 1, 3
1) Case Temperature		T_{si}	$I_F = 0, P_c = 0$	130	$^{\circ}C$	
2) Input Current		I_{si}	$P_c=0$	55	mA	
3) Electric Power (Output or Total Power Issipation)		P_{si}	-	160	mW	
Isolation Resistance (Test Voltage Between Input and Output : DC500V)		R_{ISO}	$T_a=T_{si}$	$MIN.10^9$	Ω	
			$T_a=T_{opr}(MAX.)$	$MIN.10^{11}$		
			$T_a=25^{\circ}C$	$MIN.10^{12}$		

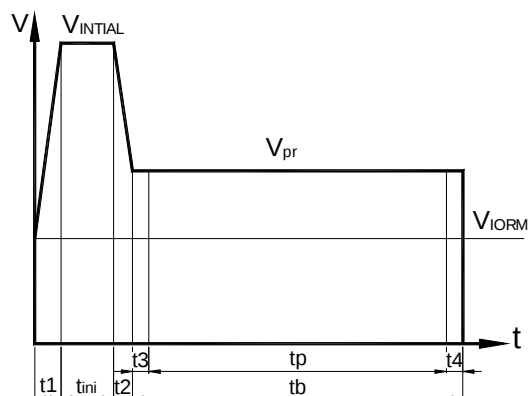
Precautions in performing isolation test

* Partial discharge test methods shall be the ones according to the specifications of VDE 0884:1992-06

* Please don't carry out isolation test (V_{iso}) over $V_{INITIAL}$,This product deteriorates isolation characteristics by partial discharge due to applying high voltage (ex. $V_{INITIAL}$). And there is possibility that this product occurs partial discharge in operating isolation voltage (V_{IORM})

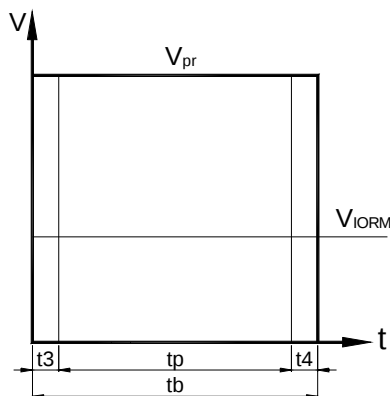
PARTIAL DISCHARGE TEST METHOD

Method (A) for type testing and random testing.



t_1, t_2 = 1 to 10s
 t_3, t_4 = 1s
 t_p (Partial Discharge Measuring Time) = 60s
 t_b = 62s
 t_{ini} = 10s

Method (B) for routine testing.



t_3, t_4 = 0.1s
 t_p (Partial Discharge Measuring Time) = 1s
 t_b = 1.2s

The partial discharge level shall not exceed 5 pC during the partial discharge measuring time interval t_p under the test conditions shown above.

CHARACTERISTICS CURVES

Fig.1 Forward Current vs. Ambient Temperature

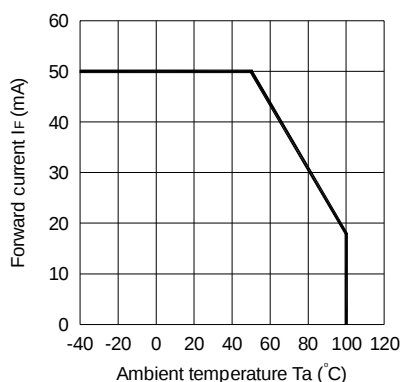


Fig.2 On-state Current vs. Ambient Temperature

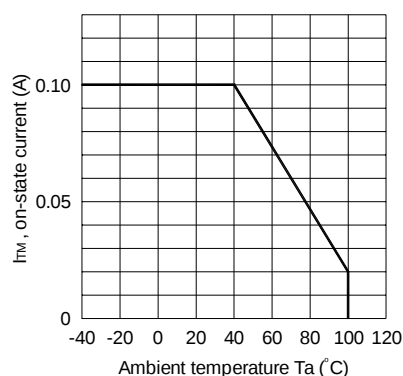


Fig.3 Minimum Trigger Current vs. Ambient Temperature

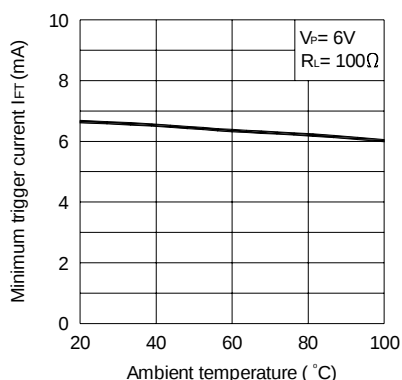


Fig.4 Forward Current vs. Forward Voltage

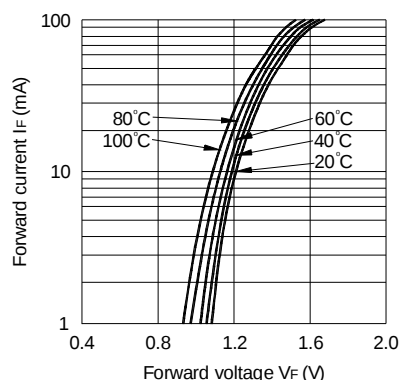


Fig.5 On-state Voltage vs. Ambient Temperature

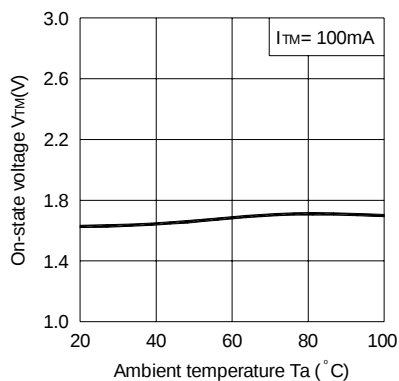
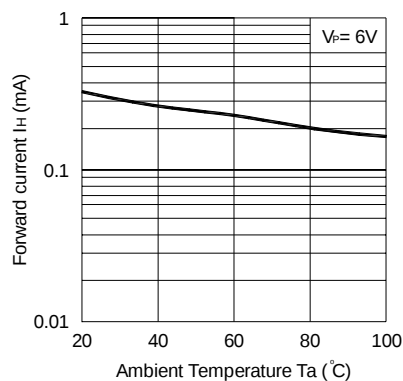


Fig.6 Holding Current vs. Ambient Temperature



CHARACTERISTICS CURVES

Fig.7 Turn-on Time vs. Forward Current

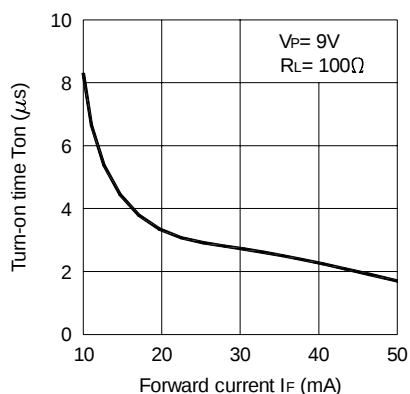


Fig.8 Repetitive Peak Off-state Current vs. Temperature

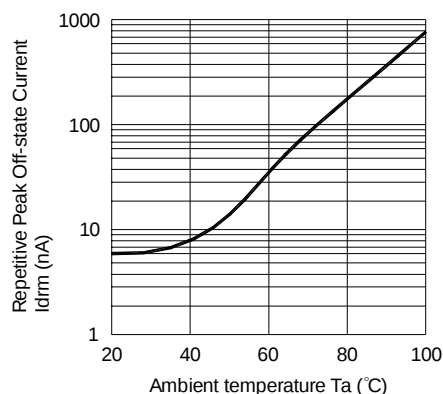
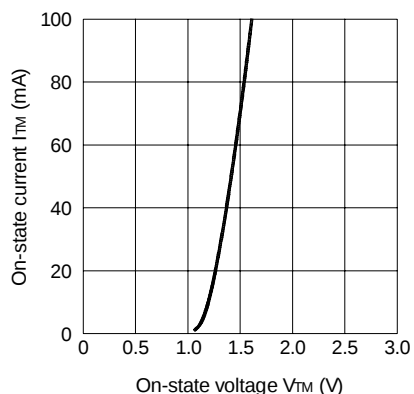
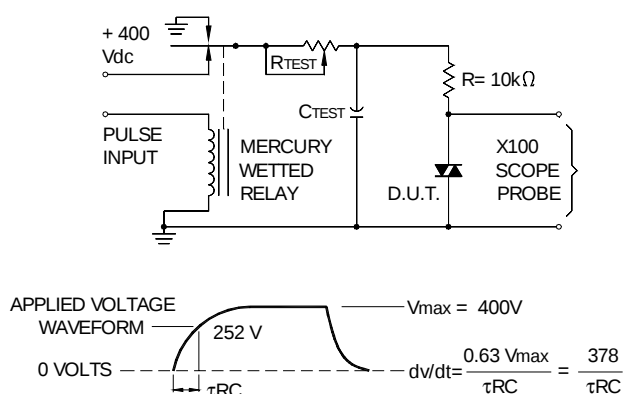


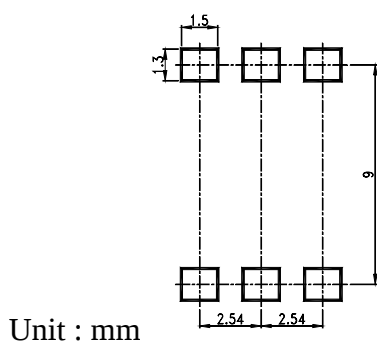
Fig.9 On-state Current vs. On-state Voltage



Static dv/dt Test Circuit



RECOMMENDED FOOT PRINT PATTERNS (MOUNT PAD)





Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

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